

BUL743

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting up to 256 W (8 x 32 W)
- Switch mode power supplies

Description

The device is manufactured using the diffused collector in planar technology adopting new and enhanced high voltage structure. It has an intrinsic ruggedness which enables the transistor to withstand an high collector current level during breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.

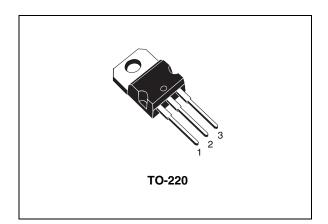
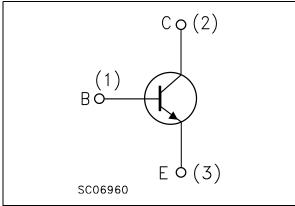


Figure 1. Internal schematic diagram



l	Order code	Marking	Package	Packaging	
Ī	BUL743	BUL743	TO-220	Tube	

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1 Electrical ratings

Table 2.	Absolute maximum	ratings
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Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	1200	V
V _{CEO}	V_{CEO} Collector-emitter voltage (I _B = 0)		V
V _{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = 6$ A, $t_p < 10$ ms)	V _{(BR)EBO}	V
Ι _C	Collector current	12	Α
I _{СМ}	Collector peak current (t _P < 5 ms)	24	Α
Ι _Β	Base current	6	Α
I _{BM}	Base peak current (t _P < 5 ms)	12	Α
P _{tot}	Total dissipation at $T_c = 25 \ ^{\circ}C$	100	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3.Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction - case	1.25	°C/W
R _{thj-amb}	Thermal resistance junction - ambient	62.5	°C/W



2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

Table 4.Electrical characteristics

Symbol	Parameter Test conditions			Turn	Max.	Unit
Symbol	ymbol Parameter Test conditions		Min.	Тур.	wax.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 1200 V		0.2	10	μA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = 500 V		10	250	μA
V _{(BR)EBO}	Emitter base breakdown voltage (I _C = 0)	I _E = 1 mA	15	19	24	V
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 50 mA	500			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter	$I_{\rm C} = 3 {\rm A}$ $I_{\rm B} = 0.6 {\rm A}$		0.15	0.5	V
CE(sat)	saturation voltage	$I_{\rm C} = 10 {\rm A}$ $I_{\rm B} = 2.5 {\rm A}$		0.6	1.5	V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 10 A I _B = 2.5 A		1.1	1.5	V
h _{FF} ⁽¹⁾	DC current gain	$I_{C} = 0.5 A$ $V_{CE} = 5 V$	35	55	80	
I'FE`'	DC current gain	$I_{\rm C} = 2 \text{ A}$ $V_{\rm CE} = 3 \text{ V}$	24	34	45	
	Resistive load	$I_{\rm C} = 6 {\rm A}$ $V_{\rm CC} = 125 {\rm V}$				
t _s	Storage time	$I_{B(on)} = -I_{B(off)} = 1.2 \text{ A}$		2.5	3.8	μs
t _f	Fall time	$t_p = 300 \ \mu s$ $V_{BE(off)} = -5 \ V$		400	500	ns
E _{ar}	Repetitive avalanche energy	L = 2 mH C = 1.8 nF V _{BE(off)} = -5 V	3			mJ

1. Pulsed duration = 300 $\mu s,$ duty cycle $\leq 1.5\%$

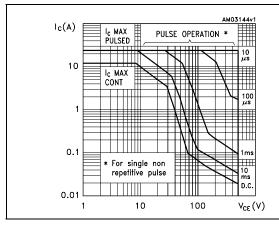


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100 125 T_{case}(°C)

2.1 **Electrical characteristics (curves)**

Figure 2. Safe operating area





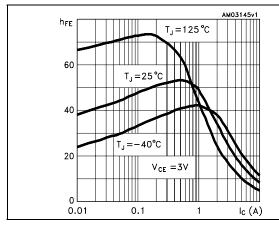
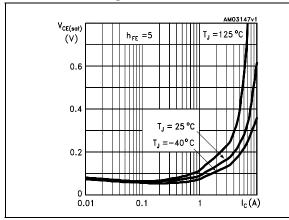
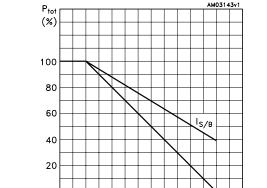


Figure 6. **Collector-emitter saturation** voltage





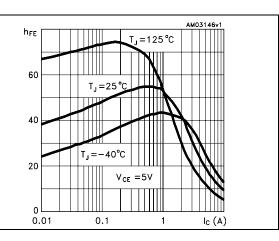
Derating curve

Figure 3.



0

25 50 75



Base-emitter saturation voltage Figure 7.

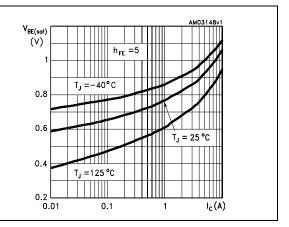




Figure 8. Output characteristics

Figure 9. Reverse biased safe operating area

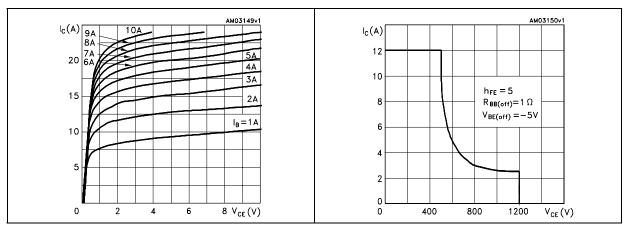
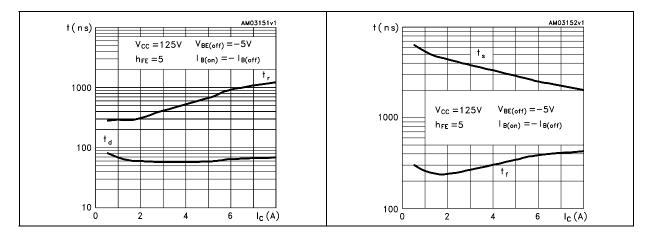


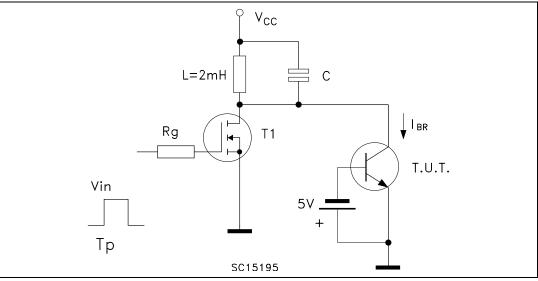
Figure 10. Resistive load switching time (on) Figure 11. Resistive load switching time (off)



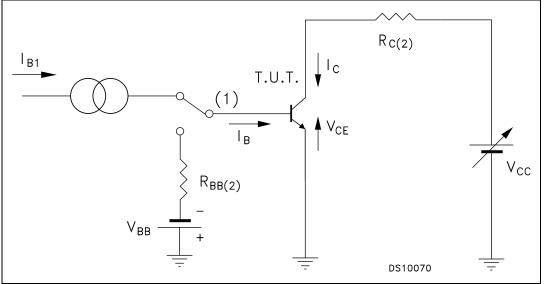


2.2 Test circuits

Figure 12.	Energy rating t	est circuit
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1. Fast electronic switch

2. Non-inductive resistor



3 Package mechanical data

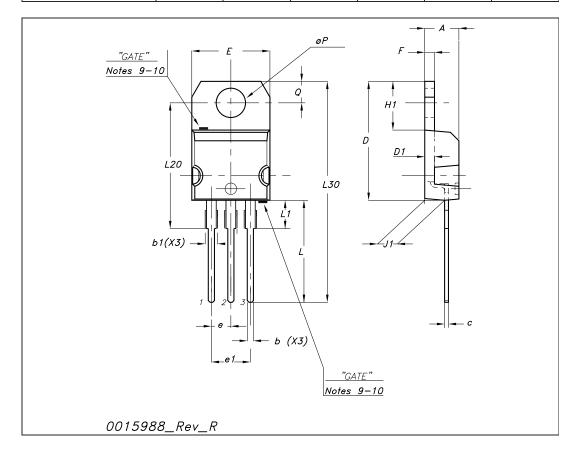
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TO-220	mechanical	data

Dim		mm		inch		
Dim	Min	Тур	Мах	Min	Тур	Max
А	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90	1		1.137	
ØP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116





4 Revision history

Table 5.Document revision history

Date	Revision	Changes
09-Dec-2008	1	First release
20-Mar-2009 2 Added Section 2.1 Section 2.1: Electrical characteristics (curr page 4		Added Section 2.1 Section 2.1: Electrical characteristics (curves) on page 4
25-May-2009 3		Document status promoted from preliminary data to datasheet



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